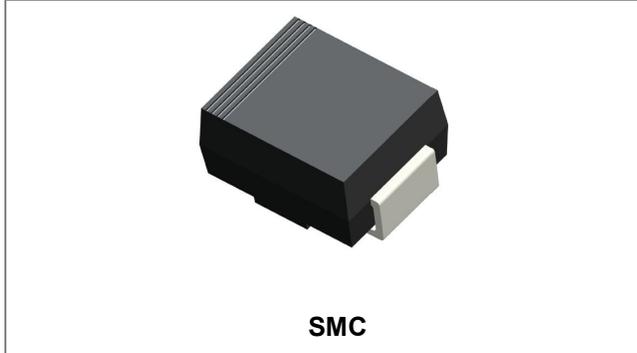


SK32 THRU SK36 SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: Low Profile Molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026 guaranteed
- Polarity: Color band or cathode Notch
- Mounting Position: Any
- Weight: 0.21grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	SK32	SK33	SK35	SK36	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	50	60	V
Maximum RMS voltage	V _{RMS}	14	21	35	42	V
Average Rectified Output Current @T _L = 75°C	I _O	3.0				A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100				A
Forward Voltage * @ I _F = 3.0 A	V _F	0.55		0.75		V
Peak Reverse Current* @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}		0.5 20			mA
Max. junction capacitance (Note 1)	C _J	150		250		pF
Typical Thermal Resistance Junction to Ambient (Note 2)	R _{θJA}	55				°C/W
Operating Temperature Range	T _J	-65 to +125				°C
Storage Temperature Range	T _{STG}	-65 to +150				°C

* Pulse width < 300 μs, duty cycle < 2%

Note: 1. Measured at 1MHz and applied reverse voltage of 5.0V D.C.
2. mounted on P.C. Board with 5.0mm² copper pad areas.

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Ratings and Characteristics Curves

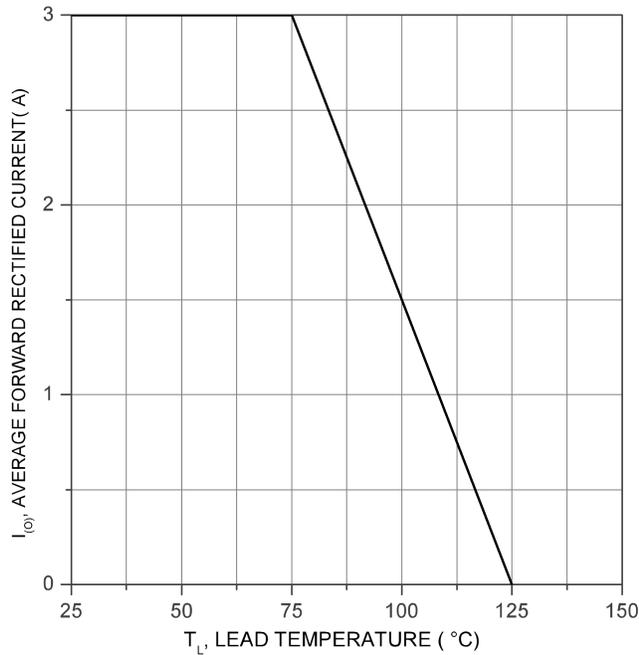


Fig.1 Forward Current Derating Curve

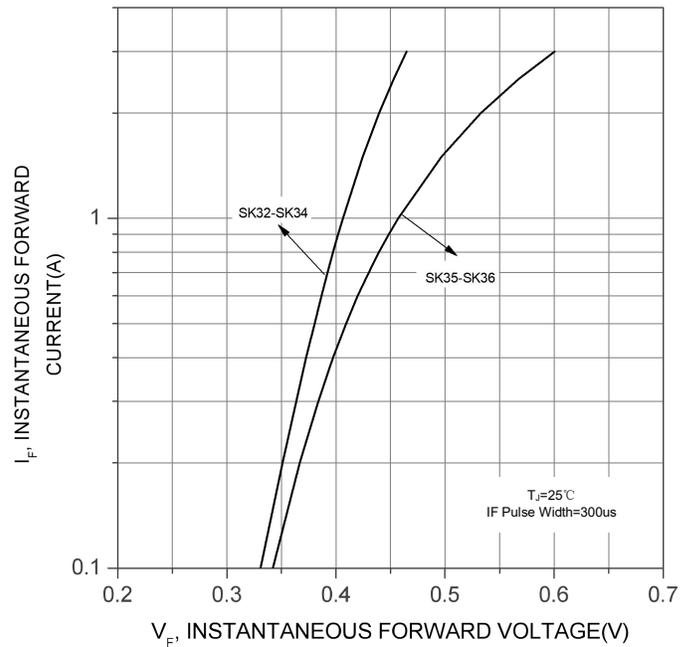


Fig.2 Typical Forward Characteristics

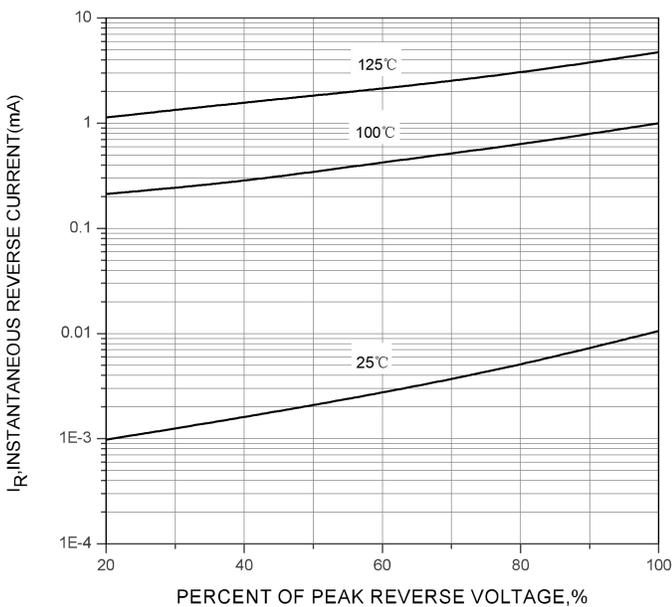


Fig.3 Typical Reverse Characteristics

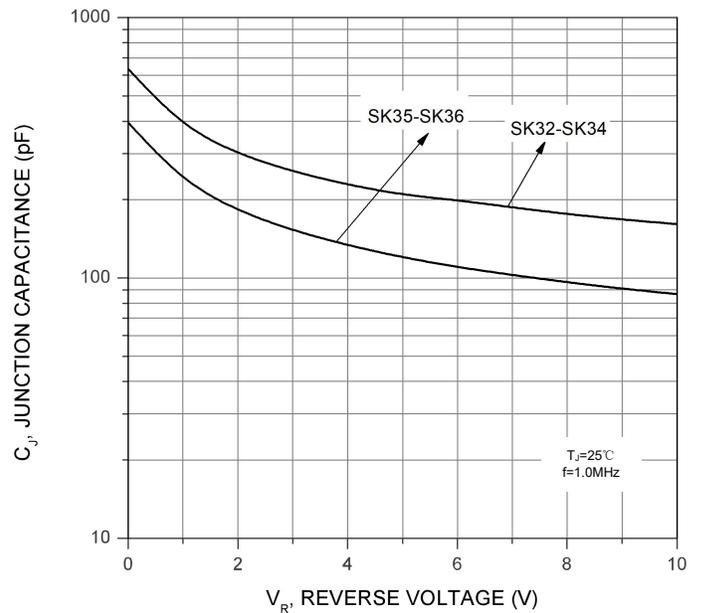
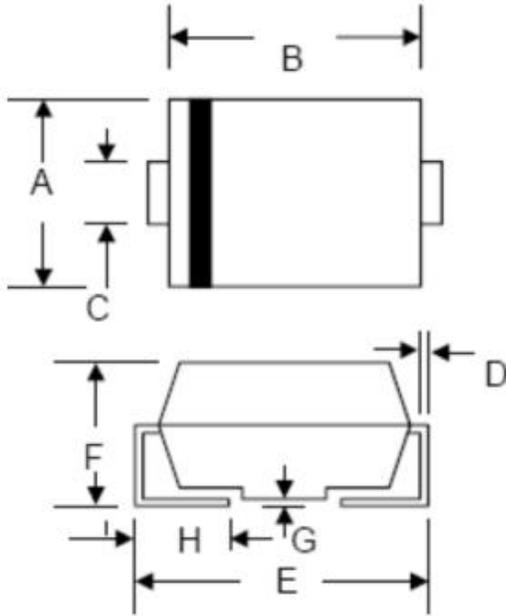


Fig.4 Typical Junction Capacitance

Mechanical Dimensions SMC



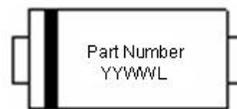
SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	5.59	6.22	0.220	0.245
B	6.60	7.11	0.260	0.280
C	2.75	3.25	0.108	0.128
D	0.152	0.305	0.006	0.012
E	7.75	8.25	0.305	0.325
F	2.00	2.95	0.079	0.116
G	0.051	0.203	0.002	0.008
H	0.76	1.60	0.030	0.063

Ordering Information

Device	Package	Shipping
SK32 THRU SK36	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

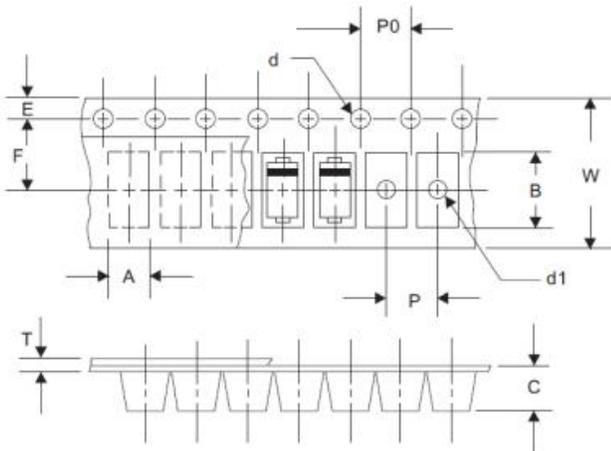
Marking Diagram



Where XXXXX is YYWWL

First row: Part Number (SK32, SK33, SK35, SK36)
Second row: YYWWL
YY is the manufacture year,
WW is the manufacture week code,
L is the wafer's Lot Number

Carrier Tape Specification SMC



SYMBOL	Millimeters	
	Min.	Max.
A	5.95	6.15
B	8.10	8.30
C	2.60	2.80
d	1.40	1.60
E	1.65	1.85
F	7.40	7.60
P	7.90	8.10
P0	3.90	4.10
T	0.20	0.40
W	15.70	16.30

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